

UNISONIC TECHNOLOGIES CO., LTD

7N90-MK6 Preliminary Power MOSFET

7A, 900V N-CHANNEL POWER MOSFET

DESCRIPTION

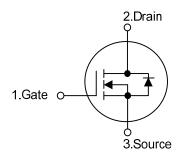
The UTC **7N90-MK6** is an N-channel mode power MOSFET using UTC's advanced technology to provide costumers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC **7N90-MK6** is universally applied in active power factor correction, electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.



- * High switching speed
- * $R_{DS(ON)}$ <2.20 @ V_{GS} =10V, I_{D} =3.5A
- * 100% avalanche tested
- * Improved dv/dt capability

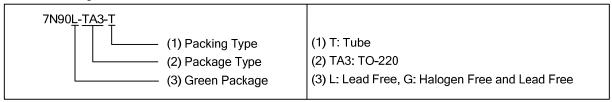
■ SYMBOL



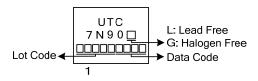
ORDERING INFORMATION

Ordering Number		Doolsons	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
7N90L-TA3-T	7N90G-TA3-T	TO-220	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



MARKING



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TO-220

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Drain to Source Voltage		V_{DSS}	900	V
Gate to Source Voltage		V_{GSS}	±30	V
Continuous Drain Current	T _C =25°C		7.0	Α
	T _C =100°C	I _D	4.4	Α
Pulsed Drain Current (Note 2)		I _{DM}	28	Α
Peak Diode Recovery dv/dt (Note 3)		dv/dt	4.0	V/ns
Power Dissipation		P_{D}	52	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature
- 3. $I_{SD} \le 7.0A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25$ °C

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ _{JC}	2.4	°C/W	

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

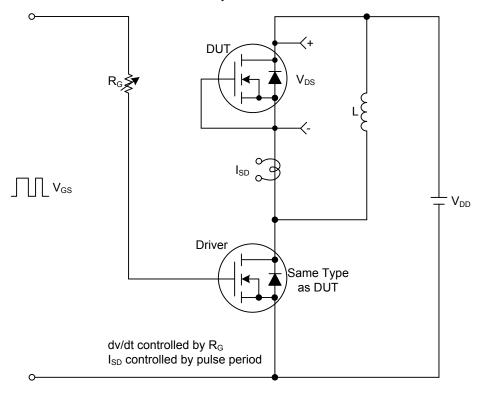
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V_{GS} =0V, I_{D} =250 μ A	900			V
Breakdown Voltage Temperature Coefficient		$\Delta BV_{DSS}/\Delta T_{J}$	I _D =250μA,Referenced to 25°C		0.96		V/°C
Drain-Source Leakage Current		I _{DSS}	V _{DS} =900V, V _{GS} =0V			10	μΑ
			V _{DS} =720V, T _C =125°C			100	μΑ
Oata Oarmaa Laaliana Ormaat	Forward	I _{GSS}	V_{DS} =0V , V_{GS} =30V			100	nA
Gate-Source Leakage Current	Reverse	I_{GSS}	V_{DS} =0V , V_{GS} =-30V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	3.0		5.0	V
Drain-Source On-State Resistance		R _{DS(ON)}	V_{GS} =10V, I_D =3.5A		1.8	2.2	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}			1450	1880	pF
Output Capacitance		Coss	V_{DS} =25V, V_{GS} =0V, f=1.0MHz		115	140	pF
Reverse Transfer Capacitance		C _{RSS}			95	110	pF
SWITCHING PARAMETERS							
Turn-ON Delay Time		t _{D(ON)}			90		ns
Turn-ON Rise Time		t _R	V_{DD} =30V, I_{D} =0.5A,		56		ns
Turn-OFF Delay Time		t _{D(OFF)}	$R_G=25\Omega$ (Note 4,5)		138		ns
Turn-OFF Fall Time		t_{F}			34		ns
SOURCE- DRAIN DIODE RATIN	NGS AND CI	HARACTERI	STICS				
Maximum Body-Diode Continuous Current Is		Is				7	Α
Maximum Body-Diode Pulsed Current		I _{SM}				28	Α
Drain-Source Diode Forward Voltage		V_{SD}	I _S =7.0A, V _{GS} =0V			1.4	V

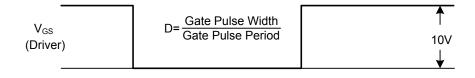
Notes: 1. Pulse Test : Pulse width ≤ 300µs, Duty cycle ≤ 2%

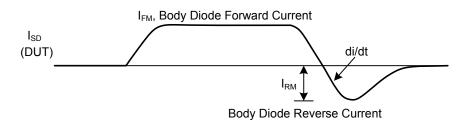
2. Essentially independent of operating temperature

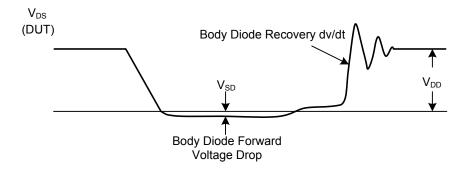
TEST CIRCUITS AND WAVEFORMS

Peak Diode Recovery dv/dt Test Circuit & Waveforms

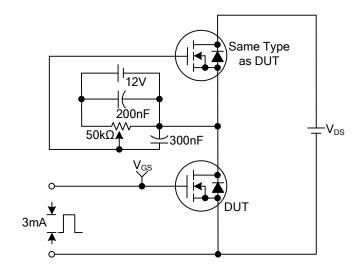




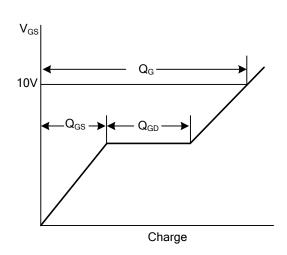




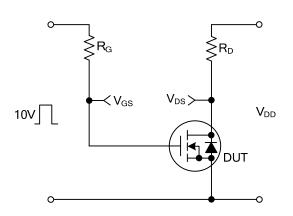
■ TEST CIRCUITS AND WAVEFORMS(Cont.)



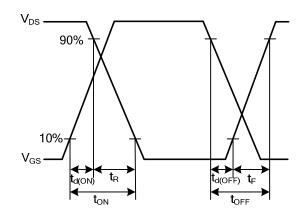
Gate Charge Test Circuit



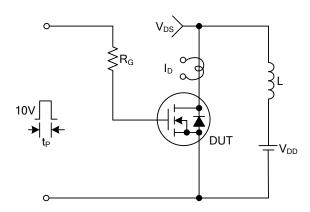
Gate Charge Waveforms



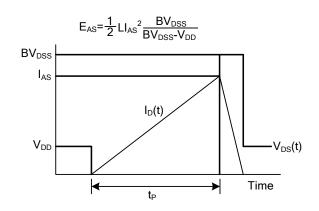
Resistive Switching Test Circuit



Resistive Switching Waveforms



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

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